NSN 5962-01-179-3629

Memory Microcircuit - Page 1 of 1



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Body Length:

1.290 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.210 inches

Maximum Power Dissipation Rating:

635.0 milliwatts

Operating Tempurature Range:

-55.0/+100.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

Features Provided:

Programmable and ultraviolet erasable and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

13 input

Case Outline Source And Designator:

D-3 mil-m-38510

Voltage Rating And Type Per Characteristic:

7.0 volts total supply

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Prom

Test Data Document:

14933-78022 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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